ISD2
ISQ2

HIGH DENSITY PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS

ROHS COMPLIANT

APPROVALS

- UL recognised, File No. E91231
  Package Code " FF "

DESCRIPTION

The IS*2 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

FEATURES

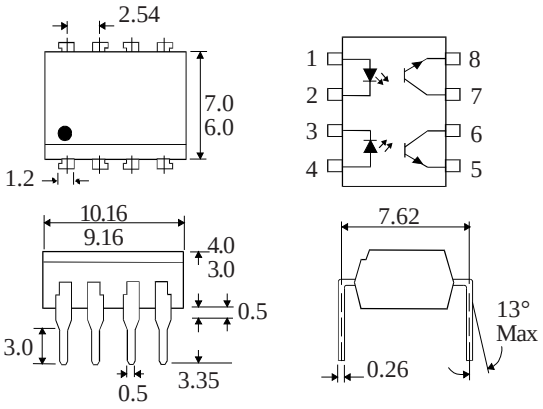
- Options :-
  10mm lead spread - add G after part no.
  Surface mount - add SM after part no.
  Tape&reel - add SMT&R after part no.
- Current Transfer Ratio (100% to 150%)
- High Isolation Voltage ($5.3kV_{RMS}$, $7.5kV_{PK}$)
- High BV_{CEO} (70V min)

APPLICATIONS

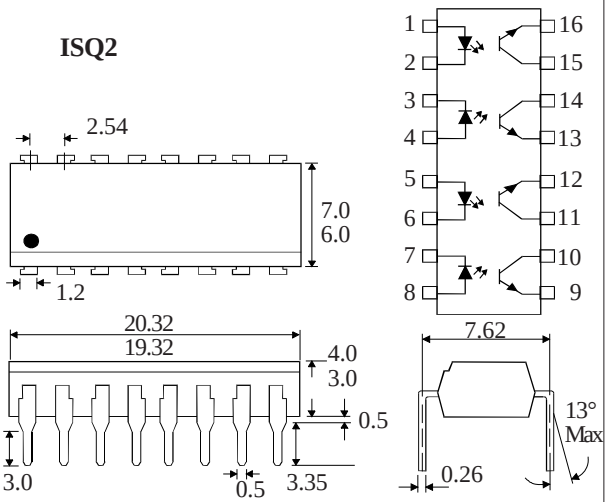
- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

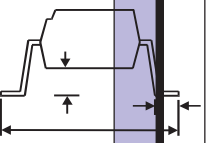
Dimensions in mm

ISD2

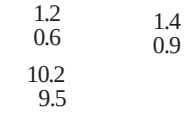


ISQ2

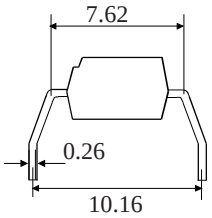




OPTION SM
SURFACE MOUNT



OPTION G



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ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	-40°C to + 125°C
Operating Temperature	-25°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}	70V
Emitter-collector Voltage BV_{ECO}	6V
Collector Current	50mA
Power Dissipation	150mW

POWER DISSIPATION

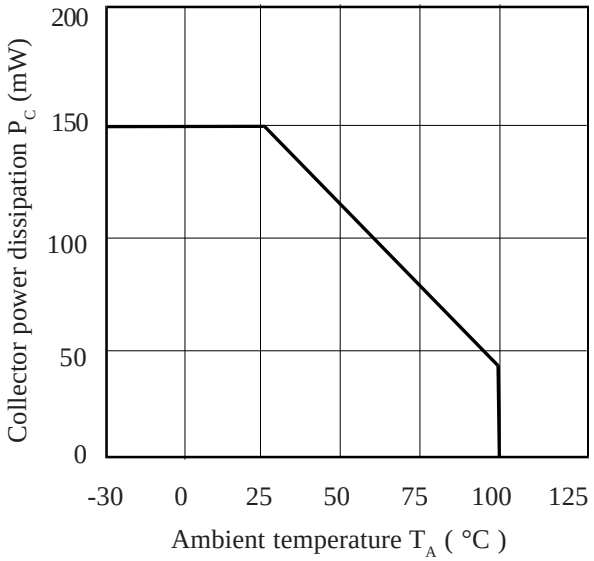
Total Power Dissipation	170mW
(derate linearly 2.67mW/°C above 25°C)	

ELECTRICAL CHARACTERISTICS (T_A = 25°C Unless otherwise noted)

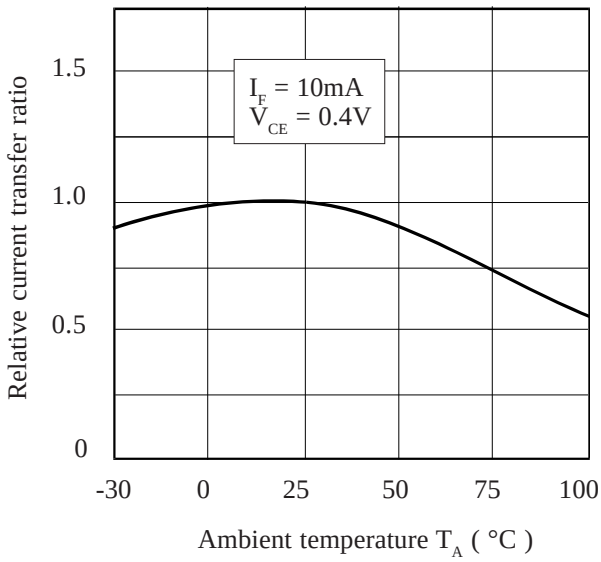
PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.65	V	I_F = 50mA
	Reverse Current (I_R)			10	µA	V_R = 4V
Output	Collector-emitter Breakdown (BV_{CEO})	70			V	I_C = 1mA
	Emitter-collector Breakdown (BV_{ECO})	6			V	I_E = 10µA
	Collector-emitter Dark Current (I_{CEO})			100	nA	V_{CE} = 20V
Coupled	Current Transfer Ratio (CTR) (Note 2)	100		500	%	10mA I_F, 10V V_{CE}
	Saturated Current Transfer Ratio		170		%	10mA I_F, 0.4V V_{CE}
	Input to Output Isolation Voltage V_{ISO} Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	See note 1 See note 1
	Input-output Isolation Resistance R_{ISO}	$5x10^{10}$			Ω	V_{IO} = 500V (note 1)
	Rise Time, tr Fall Time, tf		4 3		µs µs	I_C = 2mA V_{CE} = 2V, R_L = 100Ω

Note 1 Measured with input leads shorted together and output leads shorted together.
Note 2 Special Selections are available on request. Please consult the factory.

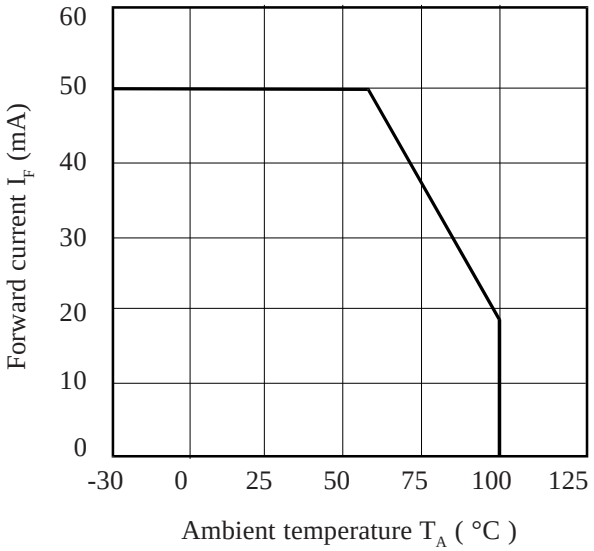
Collector Power Dissipation vs. Ambient Temperature



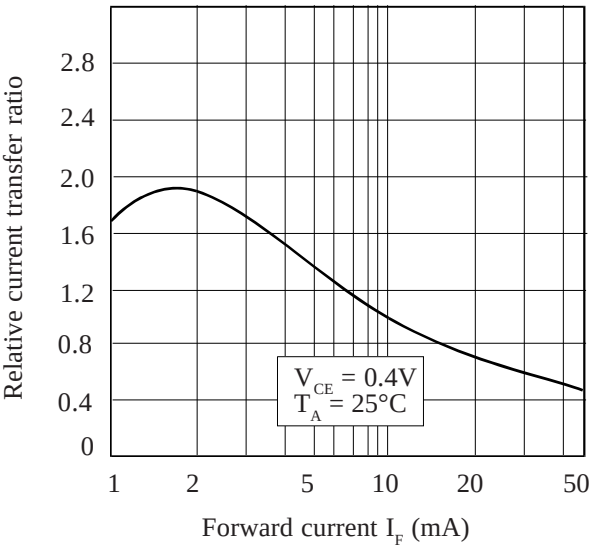
Relative Current Transfer Ratio vs. Ambient Temperature



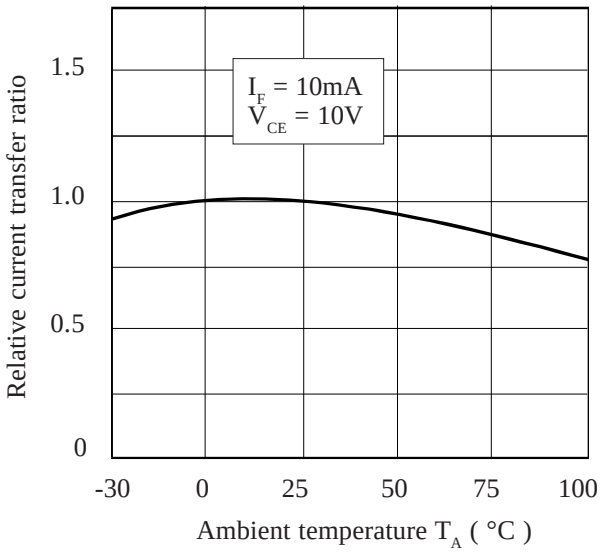
Forward Current vs. Ambient Temperature



Relative Current Transfer Ratio vs. Forward Current



Relative Current Transfer Ratio vs. Ambient Temperature



Relative Current Transfer Ratio vs. Forward Current